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# Ultralow-Noise, High PSRR, Fast, RF, 1A **Low-Dropout Linear Regulators**

## **FEATURES**

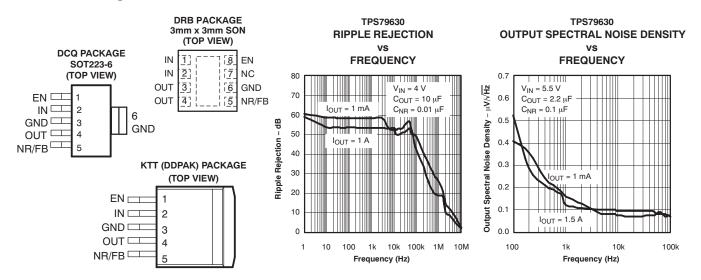
- 1A Low-Dropout Regulator With Enable
- Available in Fixed and Adjustable (1.2V to 5.5V) Versions
- High PSRR (53dB at 10kHz)
- Ultralow-Noise (40µV<sub>RMS</sub>, TPS79630)
- Fast Start-Up Time (50µs)
- Stable With a 1µF Ceramic Capacitor
- **Excellent Load/Line Transient Response**
- Very Low Dropout Voltage (250mV at Full Load, TPS79630)
- 3 x 3 SON PowerPAD™, SOT223-6, and **DDPAK-5 Packages**

#### **APPLICATIONS**

- RF: VCOs, Receivers, ADCs
- Audio
- Bluetooth™, Wireless LAN
- **Cellular and Cordless Telephones**
- Handheld Organizers, PDAs

## DESCRIPTION

The TPS796xx family of low-dropout (LDO) lowpower linear voltage regulators features high power supply rejection ratio (PSRR), ultralow-noise, fast start-up, and excellent line and load transient responses in small outline, 3 x 3 SON, SOT223-6, and DDPAK-5 packages. Each device in the family is stable with a small 1µF ceramic capacitor on the output. The family uses an advanced, proprietary BiCMOS fabrication process to yield extremely low dropout voltages (for example, 250mV at 1A). Each device achieves fast start-up times (approximately 50µs with a 0.001µF bypass capacitor) while consuming very low quiescent current (265 µA typical). Moreover, when the device is placed in standby mode, the supply current is reduced to less than 1µA. The TPS79630 exhibits approximately 40μV<sub>RMS</sub> of output voltage noise at 3.0V output, with a 0.1µF bypass capacitor. Applications with analog components that are noise sensitive, such as portable RF electronics, benefit from the high PSRR, low noise features, and the fast response time.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## ORDERING INFORMATION(1)

PRODUCT	V <sub>OUT</sub> <sup>(2)</sup>
TPS796 <b>xx <i>yyy</i> z</b>	XX is nominal output voltage (for example, 28 = 2.8V, 01 = Adjustable). YYY is package designator. Z is package quantity.

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Output voltages from 1.3V to 4.9V in 100mV increments are available; minimum order quantities may apply. Contact factory for details and availability.

# ABSOLUTE MAXIMUM RATINGS(1)

Over operating temperature range (unless otherwise noted).

	UNIT
V <sub>IN</sub> range	-0.3V to 6V
V <sub>EN</sub> range	$-0.3V$ to $V_{IN} + 0.3V$
V <sub>OUT</sub> range	6V
Peak output current	Internally limited
ESD rating, HBM	2kV
ESD rating, CDM	500V
Continuous total power dissipation	See Thermal Information Table
Junction temperature range, T <sub>J</sub>	-40°C to +150°C
Storage temperature range, T <sub>stg</sub>	−65°C to +150°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



#### THERMAL INFORMATION

	THERMAL METRIC <sup>(1)(2)</sup>	DRB	DCQ	KTT	UNITS
		8 PINS	6 PINS	5 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance (4)	47.8	70.4	25	
$\theta_{JCtop}$	Junction-to-case (top) thermal resistance (5)	83	70	35	
$\theta_{JB}$	Junction-to-board thermal resistance (6)	N/A	N/A	N/A	°C/W
ΨЈТ	Junction-to-top characterization parameter <sup>(7)</sup>	2.1	6.8	1.5	-C/W
ΨЈВ	Junction-to-board characterization parameter <sup>(8)</sup>	17.8	30.1	8.52	
$\theta_{JCbot}$	Junction-to-case (bottom) thermal resistance (9)	12.1	6.3	0.4	

- For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953A.
- For thermal estimates of this device based on PCB copper area, see the TI PCB Thermal Calculator.
- Thermal data for the DRB, DCQ, and DRV packages are derived by thermal simulations based on JEDEC-standard methodology as specified in the JESD51 series. The following assumptions are used in the simulations:

  - (a) i. DRB: The exposed pad is connected to the PCB ground layer through a 2x2 thermal via array. ii. DCQ: The exposed pad is connected to the PCB ground layer through a 3x2 thermal via array.
    - iii. KTT: The exposed pad is connected to the PCB ground layer through a 5x4 thermal via array.
  - (b) i. DRB: The top and bottom copper layers are assumed to have a 20% thermal conductivity of copper representing a 20% copper coverage.
    - ii. DCQ: Each of top and bottom copper layers has a dedicated pattern for 20% copper coverage.
    - iii. KTT: The top and bottom copper layers are assumed to have a 20% thermal conductivity of copper representing a 20% copper
  - (c) These data were generated with only a single device at the center of a JEDEC high-K (2s2p) board with 3in x 3in copper area. To understand the effects of the copper area on thermal performance, see the Power Dissipation and Estimating Junction Temperature sections of this data sheet.
- (4) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the top of the package. No specific JEDECstandard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (6) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- The junction-to-top characterization parameter,  $\psi_{JT}$ , estimates the junction temperature of a device in a real system and is extracted from the simulation data to obtain  $\theta_{JA}$  using a procedure described in JESD51-2a (sections 6 and 7).
- The junction-to-board characterization parameter, ψ<sub>JB</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data to obtain  $\theta_{JA}$  using a procedure described in JESD51-2a (sections 6 and 7).
- The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.



# **ELECTRICAL CHARACTERISTICS**

Over recommended operating temperature range ( $T_J = -40^{\circ}C$  to +125°C),  $V_{EN} = V_{IN,}$ ,  $V_{IN} = V_{OUT(nom)} + 1 V^{(1)}$ ,  $I_{OUT} = 1 mA$ ,  $C_{OUT} = 10 \mu F$ , and  $C_{NR} = 0.01 \mu F$ , unless otherwise noted. Typical values are at +25°C.

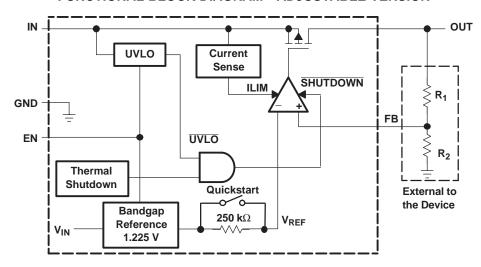
	PARAMET	ER	TEST CON	DITIONS	MIN	TYP	MAX	UNIT	
V <sub>IN</sub> Input	voltage <sup>(1)</sup>				2.7		5.5	V	
	nal reference (TF	PS79601)			1.200	1.225	1.250	V	
I <sub>OUT</sub> Cont	inuous output cu	urrent			0		1	Α	
	Output voltage range	TPS79601			1.225		5.5 – V <sub>DD</sub>	V	
O. 14m. 14		TPS79601 <sup>(2)</sup>	$0\mu A \le I_{OUT} \le 1A, V_{OUT} + 1$	/ ≤ V <sub>IN</sub> ≤ 5.5V <sup>(1)</sup>	0.98V <sub>OUT</sub>	V <sub>OUT</sub>	1.02V <sub>OUT</sub>	V	
Output voltage	Accuracy	Fixed V <sub>OUT</sub> < 5V	$0\mu A \le I_{OUT} \le 1A, V_{OUT} + 1$	/ ≤ V <sub>IN</sub> ≤ 5.5V <sup>(1)</sup>	-2.0		+2.0	%	
	Fixed V <sub>OUT</sub> = 5V		$0\mu$ A $\leq$ $I_{OUT} \leq$ 1A, $V_{OUT}$ + 1\	$/ \le V_{IN} \le 5.5V^{(1)}$	-3.0		+3.0	%	
Output vo (ΔV <sub>OUT</sub> %/	ltage line regula	ition	$V_{OUT} + 1V \le V_{IN} \le 5.5V$			0.05	0.12	%/V	
Load regu	ılation (ΔV <sub>OUT</sub> %	/ΔI <sub>OUT</sub> )	0μA ≤ I <sub>OUT</sub> ≤ 1A			5		mV	
ı		TPS79628	I <sub>OUT</sub> = 1A			270	365		
_	(2)	TPS79628DRB	$I_{OUT} = 250 \text{mA}$			52	90		
Dropout v	oltage <sup>(3)</sup> <sub>JT (nom)</sub> – 0.1V)	TPS79630	I <sub>OUT</sub> = 1A			250	345	mV	
( V IN — V O	TPS79633		I <sub>OUT</sub> = 1A			220	325		
		TPS79650	I <sub>OUT</sub> = 1A			200	300		
Output cu	rrent limit		V <sub>OUT</sub> = 0V		2.4		4.2	Α	
Ground pi	in current		0μA ≤ I <sub>OUT</sub> ≤ 1A			265	385	μΑ	
Shutdown	current <sup>(4)</sup>		$V_{EN} = 0V, 2.7V \le V_{IN} \le 5.5$	V		0.07	1	μΑ	
FB pin cu	rrent		V <sub>FB</sub> = 1.225V				1	μΑ	
			f = 100Hz, I <sub>OUT</sub> = 10mA			59			
Power-su	pply ripple		f = 100Hz, I <sub>OUT</sub> = 1A			54			
rejection	FF-7 FF	TPS79630	f = 10kHz, I <sub>OUT</sub> = 1A			53		dB	
			f = 100kHz, I <sub>OUT</sub> = 1A			42			
		1		$C_{NR} = 0.001 \mu F$		54			
		<b></b>	BW = 100Hz to 100kHz,	$C_{NR} = 0.0047 \mu F$		46			
Output no	oise voltage (TPS	579630)	I <sub>OUT</sub> = 1A	$C_{NR} = 0.01 \mu F$		41		$\mu V_{RMS}$	
				$C_{NR} = 0.1 \mu F$		40			
				$C_{NR} = 0.001 \mu F$		50			
Time, star	Time, start-up (TPS79630)		$R_L = 3\Omega$ , $C_{OUT} = 1\mu F$	$C_{NR} = 0.0047 \mu F$		75		μs	
				$C_{NR} = 0.01 \mu F$		110			
EN pin cu	rrent		V <sub>EN</sub> = 0V	· · · · · · · · · · · · · · · · · · ·	-1		1	μA	
UVLO thre			V <sub>CC</sub> rising		2.25		2.65	V	
UVLO hys	steresis					100		mV	
-	l enable input vo	oltage	2.7V ≤ V <sub>IN</sub> ≤ 5.5V	1.7		V <sub>IN</sub>	V		
	enable input vo		2.7V ≤ V <sub>IN</sub> ≤ 5.5V		0		0.7	V	

<sup>(1)</sup> Minimum  $V_{IN} = V_{OUT} + V_{DO}$  or 2.7V, whichever is greater. TPS79650 is tested at  $V_{IN} = 5.5$ V. (2) Tolerance of external resistors not included in this specification.

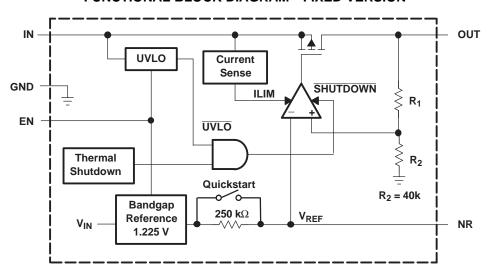
 <sup>(3)</sup> V<sub>DO</sub> is not measured for TPS79618 and TPS79625 because minimum V<sub>IN</sub> = 2.7V.
 (4) For adjustable version, this applies only after V<sub>IN</sub> is applied; then V<sub>EN</sub> transitions high to low.



#### FUNCTIONAL BLOCK DIAGRAM—ADJUSTABLE VERSION



#### FUNCTIONAL BLOCK DIAGRAM—FIXED VERSION

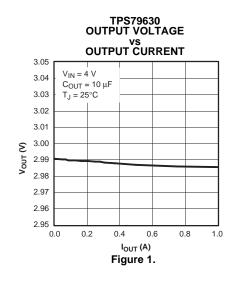


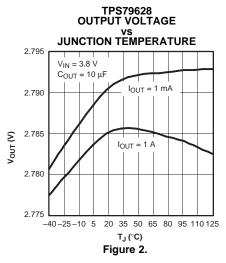
**Table 1. Terminal Functions** 

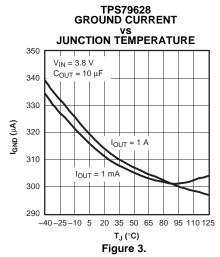
	TERMINAL		
NAME	SOT223 (DCQ) DDPAK (KTT)	SON (DRB)	DESCRIPTION
NR	5	5	Connecting an external capacitor to this pin bypasses noise generated by the internal bandgap. This improves power-supply rejection and reduces output noise.
FB	5	5	This terminal is the feedback input voltage for the adjustable device.
EN	1	8	Driving the enable pin (EN) high turns on the regulator. Driving this pin low puts the regulator into shutdown mode. EN can be connected to IN if not used.
GND	3, Tab	6, PowerPAD	Regulator ground
IN	2	1, 2	Unregulated input to the device.
OUT	4	3, 4	Output of the regulator.

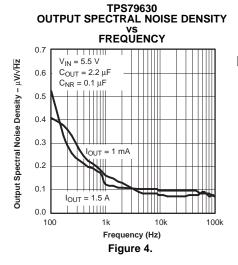


#### TYPICAL CHARACTERISTICS

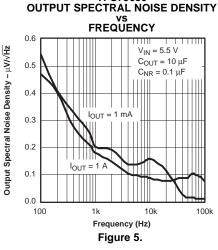




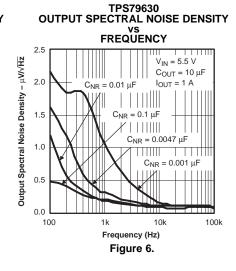


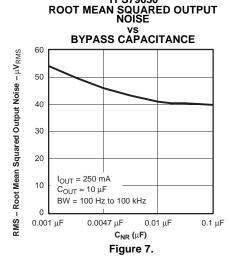


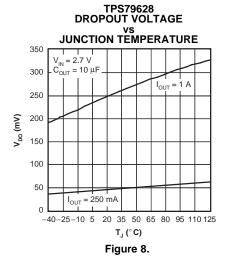
**TPS79630** 

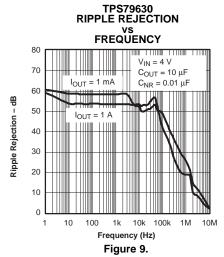


**TPS79630** 



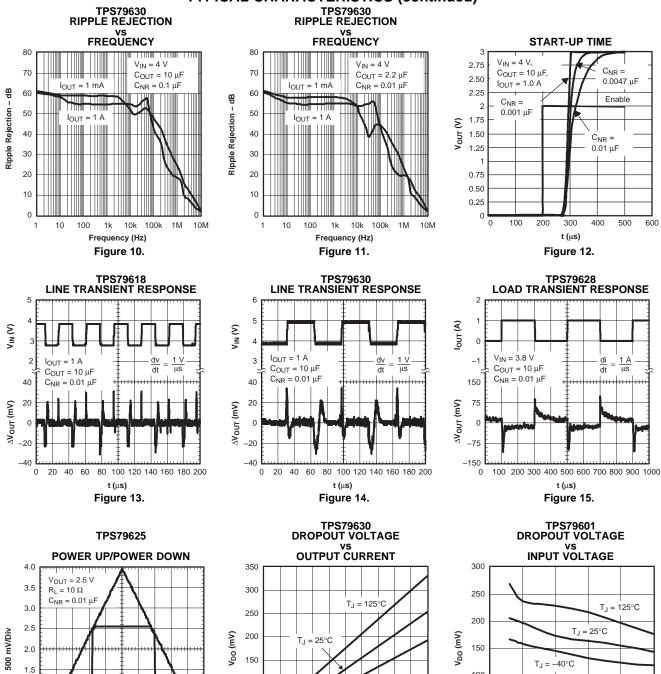








# **TYPICAL CHARACTERISTICS (continued)**



100

50

100

50

2.5

 $I_{OUT} = 1 A$ 

 $C_{OUT} = 10 \,\mu F$ 

 $C_{NR} = 0.01 \, \mu F$ 

3.0

4.0

V<sub>IN</sub> (V)

Figure 18.

4.5

5.0

 $T_J = -40^{\circ}C$ 

100 200 300 400 500 600 700 800 9001000

I<sub>OUT</sub> (mA)

Figure 17.

200  $\mu$ s/Div

Figure 16.

1.0

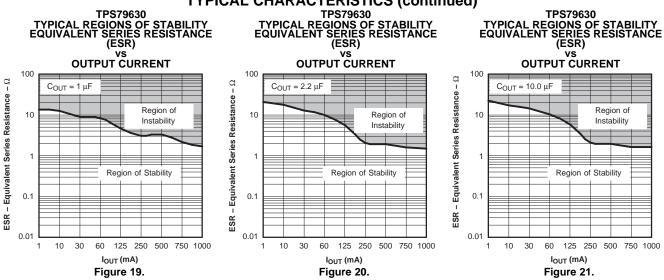
0.5

0

2 3 4 5 6



# TYPICAL CHARACTERISTICS (continued)





#### APPLICATION INFORMATION

The TPS796xx family of low-dropout (LDO) regulators has been optimized for use in noise-sensitive equipment. The device features extremely low dropout voltages, high PSRR, ultralow output noise, low quiescent current (265 $\mu$ A typically), and enable input to reduce supply currents to less than  $1\mu$ A when the regulator is turned off.

A typical application circuit is shown in Figure 22.

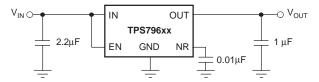


Figure 22. Typical Application Circuit

## **External Capacitor Requirements**

Although not required, it is good analog design practice to place a  $0.1\mu F$  to  $2.2\mu F$  capacitor near the input of the regulator to counteract reactive input sources. A  $2.2\mu F$  or larger ceramic input bypass capacitor, connected between IN and GND and located close to the TPS796xx, is required for stability and improves transient response, noise rejection, and ripple rejection. A higher-value input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

Like most low dropout regulators, the TPS796xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitor is  $1\mu F.$  Any  $1\mu F$  or larger ceramic capacitor is suitable.

The internal voltage reference is a key source of noise in an LDO regulator. The TPS796xx has an NR pin which is connected to the voltage reference through a 250k $\Omega$  internal resistor. The 250k $\Omega$  internal resistor, in conjunction with an external bypass capacitor connected to the NR pin, creates a lowpass filter to reduce the voltage reference noise and, therefore, the noise at the regulator output. In order for the regulator to operate properly, the current flow out of the NR pin must be at a minimum, because any leakage current creates an IR drop across the internal resistor, thus creating an output error. Therefore, the bypass capacitor must have minimal leakage current. The bypass capacitor should be no more than 0.1µF in order to ensure that it is fully charged during the guickstart time provided by the internal switch shown in the functional block diagram.

For example, the TPS79630 exhibits  $40\mu V_{RMS}$  of output voltage noise using a  $0.1\mu F$  ceramic bypass capacitor and a  $10\mu F$  ceramic output capacitor. Note that the output starts up slower as the bypass capacitance increases due to the RC time constant at the bypass pin that is created by the internal  $250k\Omega$  resistor and external capacitor.

# Board Layout Recommendation to Improve PSRR and Noise Performance

To improve ac measurements like PSRR, output noise, and transient response, it is recommended that the board be designed with separate ground planes for  $V_{\text{IN}}$  and  $V_{\text{OUT}}$ , with each ground plane connected only at the ground pin of the device. In addition, the ground connection for the bypass capacitor should connect directly to the ground pin of the device.

#### **Regulator Mounting**

The tab of the SOT223-6 package is electrically connected to ground. For best thermal performance, the tab of the surface-mount version should be soldered directly to a circuit-board copper area. Increasing the copper area improves heat dissipation.

Solder pad footprint recommendations for the devices are presented in an application bulletin *Solder Pad Recommendations for Surface-Mount Devices*, literature number AB-132, available for download from the TI web site (www.ti.com).

# Programming the TPS79601 Adjustable LDO Regulator

The output voltage of the TPS79601 adjustable regulator is programmed using an external resistor divider (see Figure 23). The output voltage is calculated using Equation 1:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right) \tag{1}$$

where:

V<sub>REF</sub> = 1.2246V typ (the internal reference voltage)

Resistors R1 and R2 should be chosen for approximately  $40\mu A$  divider current. Lower value resistors can be used for improved noise performance, but the device wastes more power. Higher values should be avoided, as leakage current at FB increases the output voltage error.



The recommended design procedure is to choose  $R2 = 30.1k\Omega$  to set the divider current at  $40\mu A$ , C1 = 15pF for stability, and then calculate R1 using Equation 2:

$$R1 = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R2$$
 (2)

In order to improve the stability of the adjustable version, it is suggested that a small compensation capacitor be placed between OUT and FB. The approximate value of this capacitor can be calculated as Equation 3:

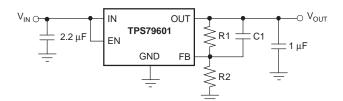
C1 = 
$$\frac{(3 \times 10^{-7}) \times (R1 + R2)}{(R1 \times R2)}$$
 (3)

The suggested value of this capacitor for several resistor ratios is shown in the table in Figure 23. If this capacitor is not used (such as in a unity-gain configuration) then the minimum recommended output capacitor is  $2.2\mu F$  instead of  $1\mu F$ .

## **Regulator Protection**

The TPS796xx PMOS-pass transistor has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (for example, during power-down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting might be appropriate.

The TPS796xx features internal current limiting and thermal protection. During normal operation, the TPS796xx limits output current to approximately 2.8A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds approximately +165°C, thermal-protection circuitry shuts it down. Once the device has cooled down to below approximately +140°C, regulator operation resumes.



# OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE	R1	R2	C1
1.8 V	14.0 kΩ	30.1 kΩ	33 pF
3.6V	57.9 kΩ	30.1 kΩ	15 pF

Figure 23. TPS79601 Adjustable LDO Regulator Programming



#### THERMAL INFORMATION

#### **POWER DISSIPATION**

Knowing the device power dissipation and proper sizing of the thermal plane that is connected to the tab or pad is critical to avoiding thermal shutdown and ensuring reliable operation.

Power dissipation of the device depends on input voltage and load conditions and can be calculated using Equation 4:

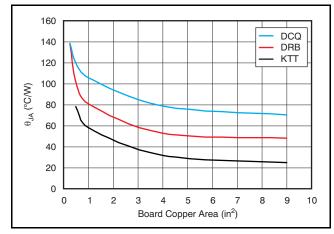
$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT}$$
(4)

Power dissipation can be minimized and greater efficiency can be achieved by using the lowest possible input voltage necessary to achieve the required output voltage regulation.

On the SON (DRB) package, the primary conduction path for heat is through the exposed pad to the printed circuit board (PCB). The pad can be connected to ground or be left floating; however, it should be attached to an appropriate amount of copper PCB area to ensure the device does not overheat. On both SOT-223 (DCQ) and DDPAK (KTT) packages, the primary conduction path for heat is through the tab to the PCB. That tab should be connected to ground. The maximum junction-to-ambient thermal resistance depends on the maximum ambient temperature, maximum device junction temperature, and power dissipation of the device and can be calculated using Equation 5:

$$R_{\theta JA} = \frac{(+125^{\circ}C - T_{A})}{P_{D}}$$
 (5)

Knowing the maximum  $R_{\theta JA}$ , the minimum amount of PCB copper area needed for appropriate heatsinking can be estimated using Figure 24.



Note:  $\theta_{JA}$  value at board size of  $9in^2$  (that is,  $3in \times 3in$ ) is a JEDEC standard.

Figure 24.  $\theta_{JA}$  vs Board Size

Figure 24 shows the variation of  $\theta_{JA}$  as a function of ground plane copper area in the board. It is intended only as a guideline to demonstrate the effects of heat spreading in the ground plane and should not be used to estimate actual thermal performance in real application environments.

**NOTE:** When the device is mounted on an application PCB, it is strongly recommended to use  $\Psi_{JT}$  and  $\Psi_{JB}$ , as explained in the *Estimating Junction Temperature* section.



#### **ESTIMATING JUNCTION TEMPERATURE**

Using the thermal metrics  $\Psi_{JT}$  and  $\Psi_{JB}$ , as shown in the *Thermal Information* table, the junction temperature can be estimated with corresponding formulas (given in Equation 6). For backwards compatibility, an older  $\theta_{JC}$ , Top parameter is listed as well.

$$\Psi_{JT}$$
:  $T_J = T_T + \Psi_{JT} \cdot P_D$   
 $\Psi_{JB}$ :  $T_J = T_B + \Psi_{JB} \cdot P_D$  (6)

Where  $P_D$  is the power dissipation shown by Equation 5,  $T_T$  is the temperature at the center-top of the IC package, and  $T_B$  is the PCB temperature measured 1mm away from the IC package *on the PCB surface* (as Figure 26 shows).

**NOTE:** Both  $T_T$  and  $T_B$  can be measured on actual application boards using a thermo-gun (an infrared thermometer).

For more information about measuring  $T_T$  and  $T_B$ , see the application note SBVA025, *Using New Thermal Metrics*, available for download at www.ti.com.

By looking at Figure 25, the new thermal metrics ( $\Psi_{JT}$  and  $\Psi_{JB}$ ) have very little dependency on board size. That is, using  $\Psi_{JT}$  or  $\Psi_{JB}$  with Equation 6 is a good way to estimate  $T_J$  by simply measuring  $T_T$  or  $T_B$ , regardless of the application board size.

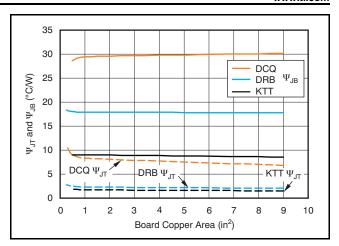
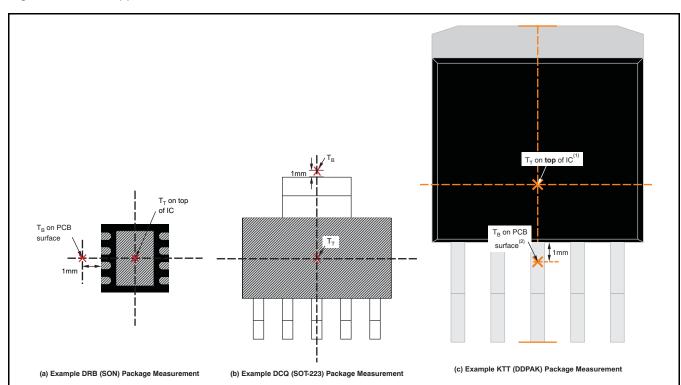


Figure 25.  $\Psi_{JT}$  and  $\Psi_{JB}$  vs Board Size

For a more detailed discussion of why TI does not recommend using  $\theta_{\text{JC(top)}}$  to determine thermal characteristics, refer to application report SBVA025, Using New Thermal Metrics, available for download at www.ti.com. For further information, refer to application report SPRA953, IC Package Thermal Metrics, also available on the TI website.



- (1) T<sub>T</sub> is measured at the center of both the X- and Y-dimensional axes.
- (2)  $T_B$  is measured  $\emph{below}$  the package lead on the PCB surface.

Figure 26. Measuring Points for T<sub>T</sub> and T<sub>B</sub>





# **REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision N (January 2011) to Revision O	Page
• Changed Power-Supply Ripple Rejection 3rd test condition from "f = 10Hz" to "f = 10kHz" (typo)	4
• Changed Power-Supply Ripple Rejection 4th test condition from "f = 100Hz" to "f = 100kHz" (typo)	4
Changes from Revision M (October 2010) to Revision N	Page
Corrected typo in front-page figure	1
Changes from Revision L (August 2010) to Revision M	Page
Corrected typo in Figure 26	12





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# **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS79601DCQ	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	PS79601	Samples
TPS79601DCQG4	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79601	Samples
TPS79601DCQR	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	PS79601	Samples
TPS79601DCQRG4	ACTIVE	SOT-223	DCQ	6		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79601	Samples
TPS79601DRBR	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CES	Samples
TPS79601DRBRG4	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CES	Samples
TPS79601DRBT	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CES	Samples
TPS79601DRBTG4	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CES	Samples
TPS79601KTT	OBSOLETE	E DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI	-40 to 125		
TPS79601KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79601	Samples
TPS79601KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79601	Samples
TPS79601KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79601	Samples
TPS79601KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79601	Samples
TPS79613DRBR	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CCT	Samples
TPS79613DRBRG4	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ССТ	Samples
TPS79613DRBT	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ССТ	Samples
TPS79613DRBTG4	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CCT	Samples





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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS79618DCQ	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79618	Samples
TPS79618DCQG4	ACTIVE	SOT-223	DCQ	6		TBD	Call TI	Call TI	-40 to 125		Samples
TPS79618DCQR	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	PS79618	Samples
TPS79618DCQRG4	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79618	Samples
TPS79618KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI	-40 to 125		
TPS79618KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR		TPS 79618	Samples
TPS79618KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR		TPS 79618	Samples
TPS79618KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79618	Samples
TPS79618KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79618	Samples
TPS79625DCQ	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79625	Samples
TPS79625DCQG4	ACTIVE	SOT-223	DCQ	6		TBD	Call TI	Call TI	-40 to 125		Samples
TPS79625DCQR	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	PS79625	Samples
TPS79625DCQRG4	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79625	Samples
TPS79625KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI	-40 to 125		
TPS79625KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR		TPS 79625	Samples
TPS79625KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR		TPS 79625	Samples
TPS79625KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79625	Samples
TPS79625KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79625	Samples



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS79628DCQ	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79628	Samples
TPS79628DCQG4	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79628	Sample
TPS79628DCQR	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79628	Sample
TPS79628DCQRG4	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79628	Sample
TPS79628DRBR	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	AMI	Sample
TPS79628DRBRG4	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	AMI	Sample
TPS79628DRBT	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	AMI	Sample
TPS79628DRBTG4	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	AMI	Sample
TPS79628KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI	-40 to 125		
TPS79628KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79628	Sample
TPS79628KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79628	Sample
TPS79630DCQ	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79630	Sample
TPS79630DCQG4	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79630	Sample
TPS79630DCQR	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79630	Sample
TPS79630DCQRG4	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79630	Sample
TPS79630KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI	-40 to 125		
TPS79630KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR		TPS 79630	Sample
TPS79630KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR		TPS 79630	Sample



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS79630KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79630	Samples
TPS79630KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79630	Samples
TPS79633DCQ	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	PS79633	Sample
TPS79633DCQG4	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79633	Samples
TPS79633DCQR	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	PS79633	Samples
TPS79633DCQRG4	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79633	Samples
TPS79633KTT	OBSOLETE	DDPAK/ TO-263	KTT	5		TBD	Call TI	Call TI	-40 to 125		
TPS79633KTTR	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR		TPS 79633	Samples
TPS79633KTTRG3	ACTIVE	DDPAK/ TO-263	KTT	5	500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79633	Samples
TPS79633KTTT	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79633	Samples
TPS79633KTTTG3	ACTIVE	DDPAK/ TO-263	KTT	5	50	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TPS 79633	Samples
TPS79650DCQ	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79650	Samples
TPS79650DCQG4	ACTIVE	SOT-223	DCQ	6	78	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79650	Samples
TPS79650DCQR	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79650	Samples
TPS79650DCQRG4	ACTIVE	SOT-223	DCQ	6	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PS79650	Samples
TPS79650DRBR	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BYZ	Samples
TPS79650DRBRG4	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BYZ	Samples
TPS79650DRBT	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BYZ	Samples



# PACKAGE OPTION ADDENDUM

16-Oct-2013

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
TPS79650DRBTG4	ACTIVE	SON	DRB	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BYZ	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL. Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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#### OTHER QUALIFIED VERSIONS OF TPS79633:

Automotive: TPS79633-Q1



# **PACKAGE OPTION ADDENDUM**

16-Oct-2013

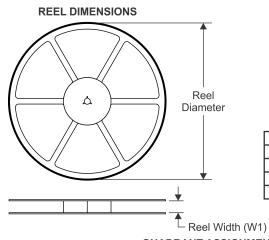
TOM	re· c	)ualified	Version	Definitions

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION



# TAPE DIMENSIONS KO P1 BO W Cavity AO

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



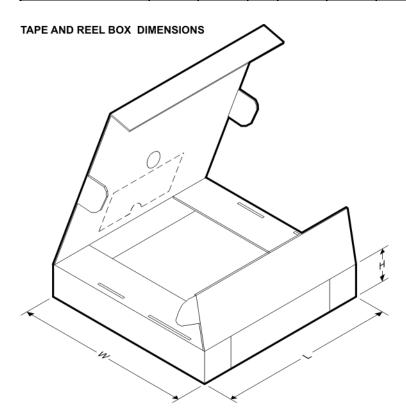
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadran
TPS79601DCQRG4	SOT-223	DCQ	6	0	330.0	12.4	7.05	7.45	1.88	8.0	12.0	Q3
TPS79601DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS79601DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS79601KTTR	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79601KTTT	DDPAK/ TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79613DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS79613DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS79618DCQRG4	SOT-223	DCQ	6	2500	330.0	12.4	7.05	7.45	1.88	8.0	12.0	Q3
TPS79618KTTR	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79618KTTT	DDPAK/ TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79625DCQRG4	SOT-223	DCQ	6	2500	330.0	12.4	7.05	7.45	1.88	8.0	12.0	Q3
TPS79625KTTR	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79625KTTT	DDPAK/ TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79628DCQR	SOT-223	DCQ	6	2500	330.0	12.4	6.8	7.3	1.88	8.0	12.0	Q3

# **PACKAGE MATERIALS INFORMATION**

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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS79628DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS79628DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS79628KTTT	DDPAK/ TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79630DCQR	SOT-223	DCQ	6	2500	330.0	12.4	6.8	7.3	1.88	8.0	12.0	Q3
TPS79630KTTR	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79630KTTT	DDPAK/ TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79633DCQRG4	SOT-223	DCQ	6	2500	330.0	12.4	7.05	7.45	1.88	8.0	12.0	Q3
TPS79633KTTR	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79633KTTT	DDPAK/ TO-263	KTT	5	50	330.0	24.4	10.6	15.6	4.9	16.0	24.0	Q2
TPS79650DCQR	SOT-223	DCQ	6	2500	330.0	12.4	6.8	7.3	1.88	8.0	12.0	Q3
TPS79650DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS79650DRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2



## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS79601DCQRG4	SOT-223	DCQ	6	0	358.0	335.0	35.0



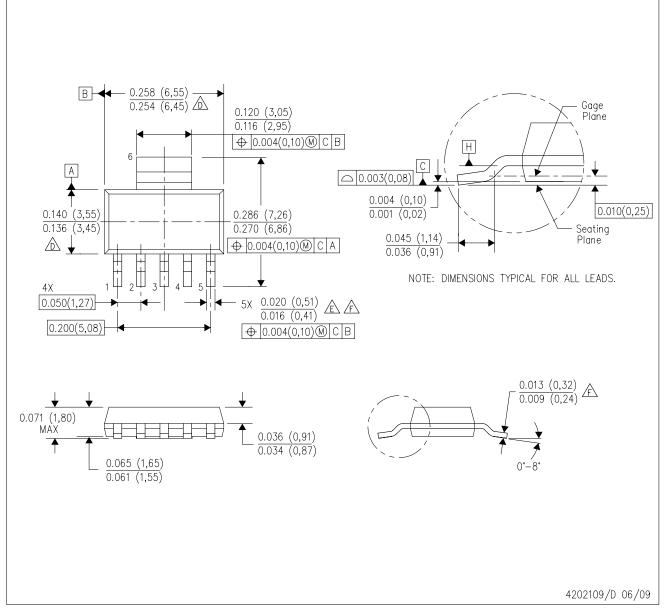
# **PACKAGE MATERIALS INFORMATION**

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS79601DRBR	SON	DRB	8	3000	367.0	367.0	35.0
TPS79601DRBT	SON	DRB	8	250	210.0	185.0	35.0
TPS79601KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS79601KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS79613DRBR	SON	DRB	8	3000	367.0	367.0	35.0
TPS79613DRBT	SON	DRB	8	250	210.0	185.0	35.0
TPS79618DCQRG4	SOT-223	DCQ	6	2500	358.0	335.0	35.0
TPS79618KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS79618KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS79625DCQRG4	SOT-223	DCQ	6	2500	358.0	335.0	35.0
TPS79625KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS79625KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS79628DCQR	SOT-223	DCQ	6	2500	358.0	335.0	35.0
TPS79628DRBR	SON	DRB	8	3000	367.0	367.0	35.0
TPS79628DRBT	SON	DRB	8	250	210.0	185.0	35.0
TPS79628KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS79630DCQR	SOT-223	DCQ	6	2500	358.0	335.0	35.0
TPS79630KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS79630KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS79633DCQRG4	SOT-223	DCQ	6	2500	358.0	335.0	35.0
TPS79633KTTR	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
TPS79633KTTT	DDPAK/TO-263	KTT	5	50	367.0	367.0	45.0
TPS79650DCQR	SOT-223	DCQ	6	2500	358.0	335.0	35.0
TPS79650DRBR	SON	DRB	8	3000	367.0	367.0	35.0
TPS79650DRBT	SON	DRB	8	250	210.0	185.0	35.0

# DCQ (R-PDSO-G6)

# PLASTIC SMALL-OUTLINE



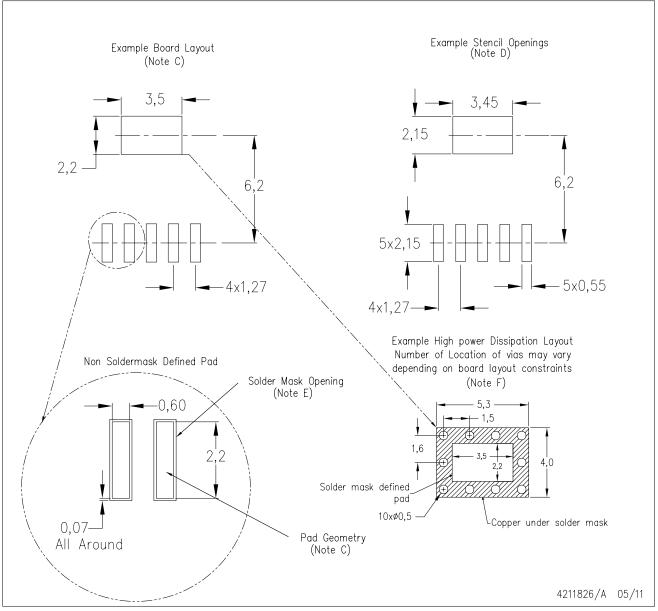
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Controlling dimension in inches.
- Body length and width dimensions are determined at the outermost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs, and interlead flash, but including any mismatch between the top and the bottom of the plastic body.
- Lead width dimension does not include dambar protrusion.
- Lead width and thickness dimensions apply to solder plated leads.
- G. Interlead flash allow 0.008 inch max.
- H. Gate burr/protrusion max. 0.006 inch.
- I. Datums A and B are to be determined at Datum H.



# DCQ (R-PDSO-G6)

# PLASTIC SMALL OUTLINE



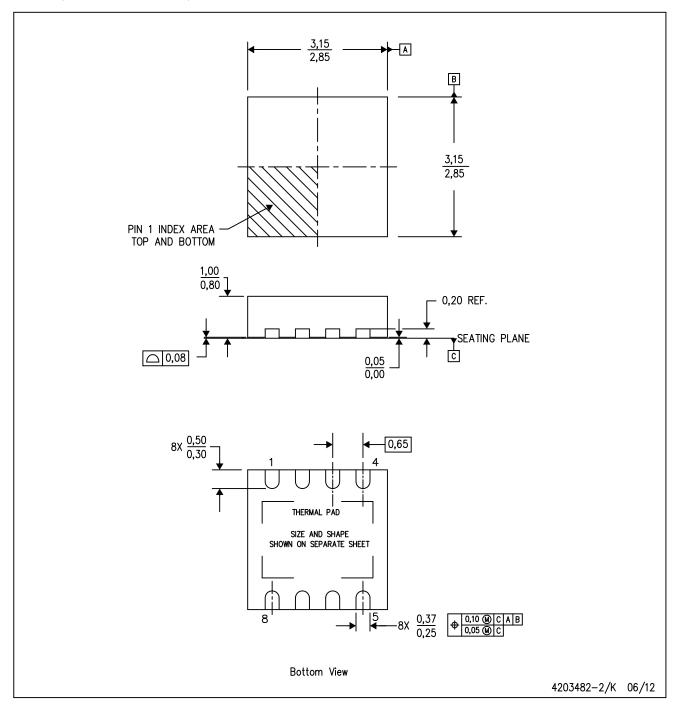
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
- F. Please refer to the product data sheet for specific via and thermal dissipation requirements.



DRB (S-PVSON-N8)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Small Outline No-Lead (SON) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.



# DRB (S-PVSON-N8)

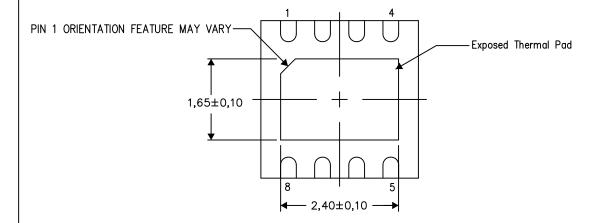
# PLASTIC SMALL OUTLINE NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

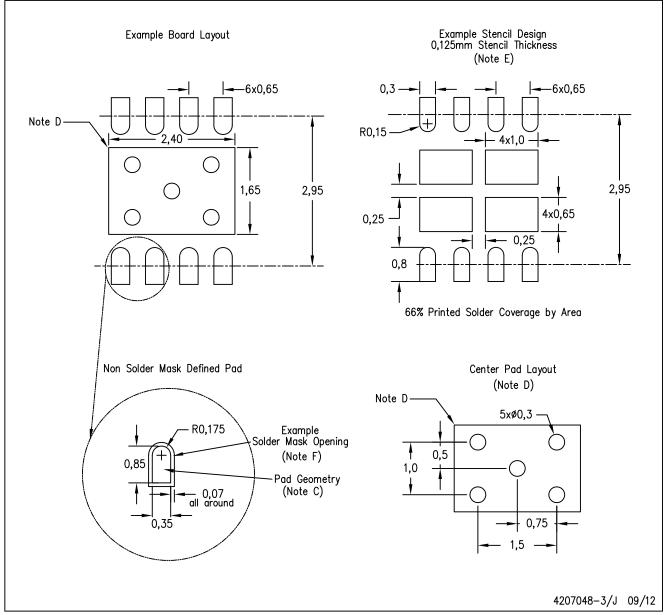
4206340-3/N 09/12

NOTE: All linear dimensions are in millimeters



# DRB (S-PVSON-N8)

# PLASTIC SMALL OUTLINE NO-LEAD



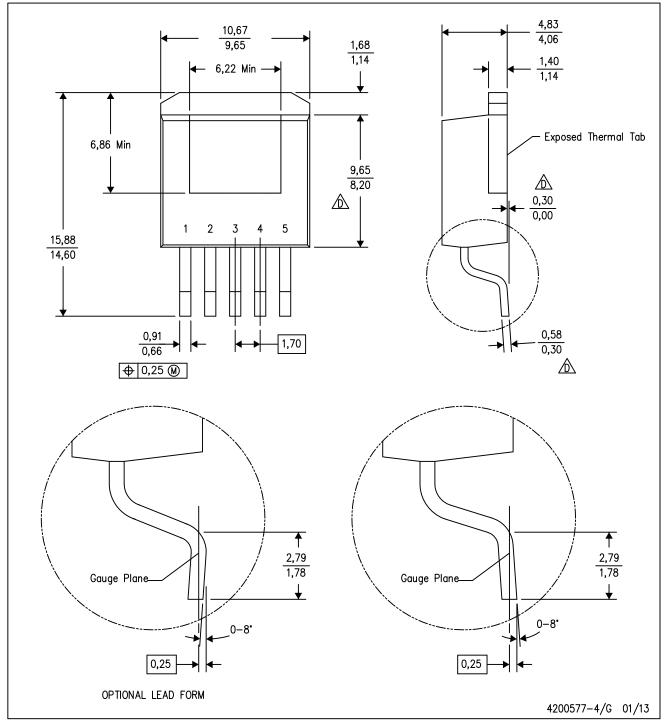
NOTES: A

- S: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">https://www.ti.com</a>.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - F. Customers should contact their board fabrication site for solder mask tolerances.



# KTT (R-PSFM-G5)

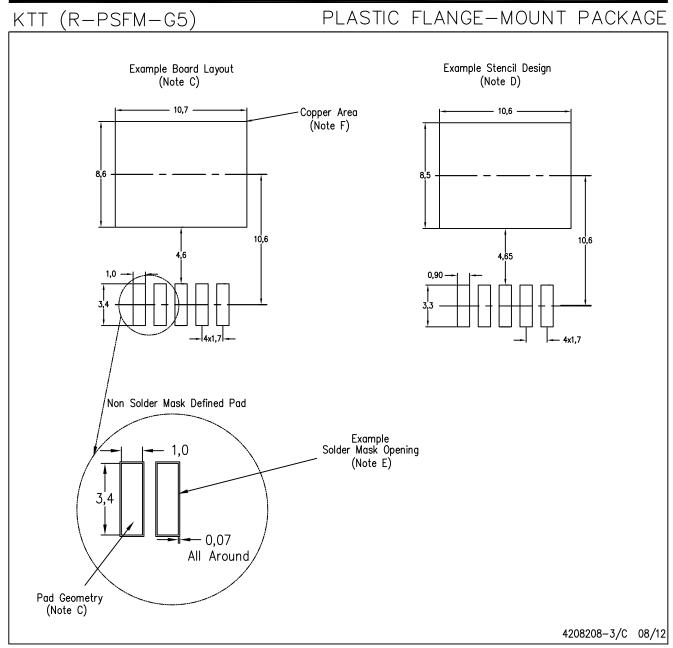
# PLASTIC FLANGE-MOUNT PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.
- Falls within JEDEC T0—263 variation BA, except minimum lead thickness, maximum seating height, and minimum body length.





NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.

  Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
- F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.



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